16kbit serial ferroelectric memory BR24CF16F

The BR24CF16F is a non-volatile ferroelectric memory developed for use in ROHM's non-volatile memory technology and ferroelectric technology. Using a ferroelectric memory enables faster writing speeds than EEPROM and flash memories, increases the number of times that rewriting can be carried out, and reduces the power consumption. This product is compatible with general-purpose EEPROM memory hardware (supports the I²C BUS) and software.

Applications

Portable equipment (PDAs, etc.), memory backup units for game machines, cable TVs, displays, printers,

Features

- 1) Non-volatile random access memory
- 2) Rewriting possible up to 10¹² times
- 3) No waiting time when writing data

facsimile machines, TVs, cameras, and other office automation equipment

- 4) Data can be retained for up to ten years
- 5) Supports 2 wire serial interface (I²C BUS)
- Low current consumption (100 µ A max., in normal mode)

Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	Vcc	-0.3~7.0	V
Power dissipation	Pd	350*	mW
Operating temperature	Topr	-40~85	Ĉ
Storage temperature	Tstg	65~125	°C

* Reduced by 3.5mW for each increase in Ta of 1°C over 25°C.

Recommended operating conditions

Parameter	Symbol	Limits	Unit	
Power supply voltage	Vcc	4.5~5.5	v	
Input voltage	Vin	0~Vcc	v	

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Pin descriptions

Pin Name	I/O	Function	
Vcc	—	Power supply.	
GND	_	Reference voltage for all inputs and outputs: 0 V(Ground)	· · ·
SCL	Input	Serial clock input	
SDA	Input/output	Slave and word address, serial data output	
WP	Input	Hardware and Write Protect pin	
NC		No connected	

* The SDA pin is Nch open drain output, so an external pull-up resistance should be added.

Input/output equivalent circuits







•Electrical characteristics (Unless otherwise noted, Ta = -40 to 85°C, Vcc = 4.5 to 5.5V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	Measurement Circuit
"H" input voltage	VIH	0.7VCC	_	-	٧		
"L" input voltage	VIL		_	0.3VCC	٧		
"L" output voltage	VOL		-	0.4	V	IOL=3.0mA (SDA)	Fig.1
Input leakage current	ILI	1	_	1	μA	VIN=0V~Vcc	Fig.2
Output leakage current	ILO	1	_	1	μA	VOUT=0V~Vcc	Fig.2
			60	100	μA	fSCL=100kHz CMOS input	Fig.3
Operating current consumption	ICC		180	300	μA	fSCL=400kHz CMOS input	Fig.3
Standby current	ISB		16	60	μA	SCL SDA=VCC	Fig.4
			_	100	kHz		
SCL frequency	fSCL		_	400	kHz		

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●Operation timing characteristics (Unless otherwise noted, Ta=-40 to 85°C, Vcc=4.5 to 5.5	51/1
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· · · · · · · · · · · · · · · · · · ·		rise noted, Ta=-40 to 85°C, Vcc=4.3				fSCL=400kHz		1	MemorylCo
Parameter	Symbol	Min.	Тур.	Max.	Min.	Typ.	Max.	Unit	
Data clock "H" time	tHIGH	4.0		_	0.6			μS	· I
Data clock "L" time	tLOW	4.7	_	_	1.3	_		μS	· I
SDA/SCL rise time	tR	_		1.0	_		0.3	μS	
SDA/SCL fall time	tF		_	0.3	-	_	0.3	μS	
Start condition hold time	tHD:STA	4.0	_	_	0.6	_	_	μS	
Start condition setup time	tSU:STA	4.7	_	_	0.6	_	_	μS	
Input data hold time	tHD:DAT	0		-	0	_	_	nS	
nput data setup time	tSU:DAT	250		—	100	_	_	nS	_
Output data "L" delay time	tPDO	_	_	3.0	_		3.0	μS	
Output data hold time	tDH	0	-	_	0		_	μS	
Stop condition setup time	tSU:STO	4.0	_	-	0.6	_	_	μS	emory
Bus release time before transmission starts	tBUF	4.7	_	_	1.3			μS	ric m
Noise reduction valid period (SCL/SDA pins)	ti	_	_	50		_	50	nS	⁻ erroelectric memory

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Reading of input data begins at the rising edge of SCL. Data output is synchronized to the falling edge of SCL.

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Fig.3 Current dissipation measurement circuit

Fig.4 Standby current measurement circuit

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- Circuit operation
- Start condition (acknowledgement of start bit)

Before executing any command, a start condition (start bit) must be input. When SCL is HIGH, a start condition causes SDA to fall from HIGH to LOW. No command input will be accepted unless this start condition is input.

- Stop condition (acknowledgement of stop bit)
 To stop any command, a stop condition (stop bit) is required. A stop condition is achieved when SDA goes from LOW to HIGH while SCL is HIGH.
- · Precautions concerning write commands
- With the Write command, writing of the data begins when the stop bit is input, after the data has been input. • Device addressing (specifying the slave address)
- Make sure the slave address is output from the master immediately after the start condition.

The upper four bits of the slave address are used to determine the device type. The device code for this IC is fixed at "1010". The next three bits of the slave address (PS2 \sim 0) are used to select the page. The 16KB memory is configured of 256 bytes \times 8 pages, and the page to be accessed is selected by specifying PS2 \sim 0. The lower most bit of the slave address (R/W) is used to set the write or read mode as follows.

R/W set to 0 ····· Write or random read

R/W set to 1·····Read

Device Type	Page Select	
1010	PS2 PS1 PS0	R/₩

• WP (Write Protect pin)

Setting the WP pin to Vcc (HIGH) inhibits writing of data to the upper four pages (pages 4 to 7) of the eight available pages. Setting the WP pin to GND (LOW) enables normal writing operations.

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ACK signal

The acknowledge signal (ACK signal) is determined by software and is used to indicate whether or not a data transfer is proceeding normally. The transmitting device, whether the master or slave, opens the bus after an 8-bit data output (the master when a write or read command of the slave address is input; the BR24CF16F when reading data). For the receiving device during the ninth clock cycle, SDA is set to LOW and an acknowledge signal (ACK signal) is sent to indicate that it received the 8-bit data (the master when a write command or a read command is input to a slave address, the BR24CF16F when a read command is output).

When data is being written to this IC, a LOW acknowledge signal (ACK signal) is output after the receipt of each eight bits of data (word address and write data).

When data is being read from the IC, eight bits of data (read data) are output and the IC waits for a returned LOW acknowledge signal (ACK signal). When an acknowledge signal (ACK signal) is detected and a stop condition is not sent from the master side, the IC continues to output data. If an acknowledge signal (ACK signal) is not detected, the IC interrupts the data transfer and ceases reading operations after recognizing the stop condition (stop bit). The IC then enters the waiting or standby state.

(See Figure 5 for acknowledge signal (ACK signal) response.)



Fig.5 Acknowledge signal (ACK signal) response (during write and read slave address input)

Timing charts





- Data is written to the address designated by the WA7~WA0, on the page specified by PS2~PS0.
- · After eight bits of data are input, the data is written to the memory cell by issuing the stop bit.



Fig.7 Multi-byte write cycle

- To write data to consecutive addresses, the Multi Byte Write command can be used to omit input of the address.
- If data is input after the ACK signal which follows the normal Byte Write command, that data is written to the (specified address + 1) address.
- The Multi Byte Write command remains valid until a stop condition is input, with no restriction on the number of bytes.

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Timing charts



Fig. 8 Current read cycle

- · This IC increments the address by one position by using the internal circuit address count. It records the finalword address (n address) of the executed write - read command.
- · This command reads the data of the next word address (n + 1 address) of the final write word address after the execution of the previous command.
- When an ACK signal LOW is detected after DO and a stop condition is not sent from the master (μ-COM), the next word address data can be read. (See Figure 10 for the sequential read cycle.)
- · This command is ended by inputting HIGH to the ACK signal after DO and raising the SDA signal (stop condition) by setting SCL to HIGH.





- · This command can read the designated word address data.
- When an ACK signal LOW is detected after DO and a stop condition is not sent from the master (μ-COM), the next word address data can be read. (See Figure 10 for the sequential read cycle.)
- · This command is ended by inputting a HIGH signal to the ACK signal after DO and raising the SDA signal (stop condition) by raising SCL to HIGH.

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Timing charts



- When an ACK signal LOW is detected after DO and a stop condition is not sent from the master (μ-COM), the next word address data can be read.
- This command is ended by inputting a HIGH signal to the ACK signal after DO and raising the SDA signal (stop condition) using the SCL signal HIGH.
- · Sequential reading can also be done with a random read.

External dimensions (Units: mm)



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